

iscN-Channel MOSFET Transistor

TK12A50D5, ITK12A50D5

• FEATURES

Low drain-source on-resistance:
R_{DS}(ON) = 0.5Ω (typ.)

Enhancement mode:
Vth = 2.5 to 4.5V (VDS = 10 V, ID=1.0mA)

- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

· Switching Voltage Regulators

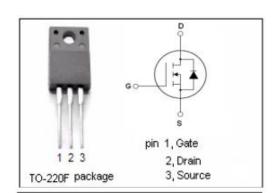


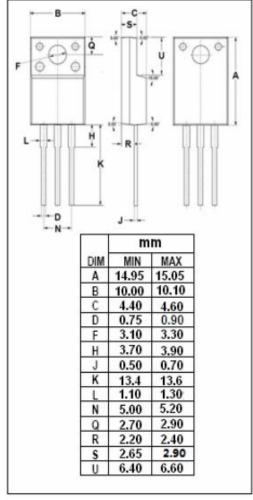
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	500	V
V _{GS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous	12	А
I _{DM}	Drain Current-Single Pulsed	48	А
P _D	Total Dissipation @T _C =25℃	45	W
Tj	Max. Operating Junction Temperature	150	${\mathbb C}$
T _{stg}	Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.78	°C/W
Rth(ch-a)	h(ch-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	500			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D =1.0mA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =6A		500	730	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} =500V; V _{GS} = 0V			10	μА
V _{SDF}	Diode forward voltage	I _{DR} =12A, V _{GS} = 0 V			1.9	V

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